

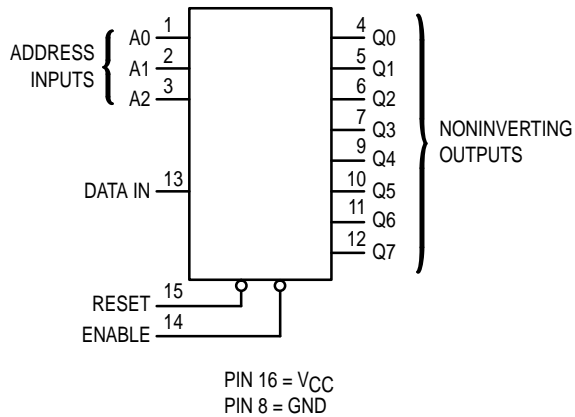
8-Bit Addressable Latch 1-of-8 Decoder High-Performance Silicon-Gate CMOS

The MC54/74HC259 is identical in pinout to the LS259. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

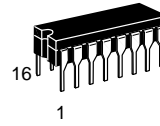
The HC259 has four modes of operation as shown in the mode selection table. In the addressable latch mode, the data on Data In is written into the addressed latch. The addressed latch follows the data input with all non-addressed latches remaining in their previous states. In the memory mode, all latches remain in their previous state and are unaffected by the Data or Address inputs. In the one-of-eight decoding or demultiplexing mode, the addressed output follows the state of Data In with all other outputs in the LOW state. In the Reset mode all outputs are LOW and unaffected by the address and data inputs. When operating the HC259 as an addressable latch, changing more than one bit of the address could impose a transient wrong address. Therefore, this should only be done while in the memory mode.

- Output Drive Capability: 10 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2 to 6 V
- Low Input Current: 1 μ A
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 202 FETs or 50.5 Equivalent Gates

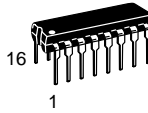
LOGIC DIAGRAM



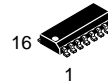
MC54/74HC259



J SUFFIX
CERAMIC PACKAGE
CASE 620-10



N SUFFIX
PLASTIC PACKAGE
CASE 648-08



D SUFFIX
SOIC PACKAGE
CASE 751B-05

ORDERING INFORMATION

| | |
|------------|---------|
| MC54HCXXXJ | Ceramic |
| MC74HCXXXN | Plastic |
| MC74HCXXXD | SOIC |

PIN ASSIGNMENT

| | | | |
|-----|---|----|---------|
| A0 | 1 | 16 | VCC |
| A1 | 2 | 15 | RESET |
| A2 | 3 | 14 | ENABLE |
| Q0 | 4 | 13 | DATA IN |
| Q1 | 5 | 12 | Q7 |
| Q2 | 6 | 11 | Q6 |
| Q3 | 7 | 10 | Q5 |
| GND | 8 | 9 | Q4 |

MODE SELECTION TABLE

| Enable | Reset | Mode |
|--------|-------|----------------------|
| L | H | Addressable Latch |
| H | H | Memory |
| L | L | 8-Line Demultiplexer |
| H | L | Reset |

LATCH SELECTION TABLE

| Address Inputs | | | Latch Addressed |
|----------------|---|---|-----------------|
| C | B | A | |
| L | L | L | Q0 |
| L | L | H | Q1 |
| L | H | L | Q2 |
| L | H | H | Q3 |
| H | L | L | Q4 |
| H | L | H | Q5 |
| H | H | L | Q6 |
| H | H | H | Q7 |



MAXIMUM RATINGS*

| Symbol | Parameter | Value | Unit |
|------------------|---|--------------------------------|------|
| V _{CC} | DC Supply Voltage (Referenced to GND) | - 0.5 to + 7.0 | V |
| V _{in} | DC Input Voltage (Referenced to GND) | - 1.5 to V _{CC} + 1.5 | V |
| V _{out} | DC Output Voltage (Referenced to GND) | - 0.5 to V _{CC} + 0.5 | V |
| I _{in} | DC Input Current, per Pin | ± 20 | mA |
| I _{out} | DC Output Current, per Pin | ± 25 | mA |
| I _{CC} | DC Supply Current, V _{CC} and GND Pins | ± 50 | mA |
| P _D | Power Dissipation in Still Air, Plastic or Ceramic DIP† SOIC Package† | 750 500 | mW |
| T _{stg} | Storage Temperature | - 65 to + 150 | °C |
| T _L | Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package) (Ceramic DIP) | 260 300 | °C |

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND ≤ (V_{in} or V_{out}) ≤ V_{CC}. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

* Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

† Derating — Plastic DIP: - 10 mW/°C from 65° to 125°C
Ceramic DIP: - 10 mW/°C from 100° to 125°C
SOIC Package: - 7 mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit | |
|------------------------------------|--|---|-----------------|--------------------|----|
| V _{CC} | DC Supply Voltage (Referenced to GND) | 2.0 | 6.0 | V | |
| V _{in} , V _{out} | DC Input Voltage, Output Voltage (Referenced to GND) | 0 | V _{CC} | V | |
| T _A | Operating Temperature, All Package Types | - 55 | + 125 | °C | |
| t _r , t _f | Input Rise and Fall Time (Figure 1) | V _{CC} = 2.0 V V _{CC} = 4.5 V V _{CC} = 6.0 V | 0 0 0 | 1000 500 400 | ns |

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

| Symbol | Parameter | Test Conditions | V _{CC} V | Guaranteed Limit | | | Unit |
|-----------------|--|--|----------------------|------------------|--------|---------|------|
| | | | | - 55 to 25°C | ≤ 85°C | ≤ 125°C | |
| V _{IH} | Minimum High-Level Input Voltage | V _{out} = 0.1 V or V _{CC} - 0.1 V I _{out} ≤ 20 μA | 2.0 | 1.5 | 1.5 | 1.5 | V |
| | | | 4.5 | 3.15 | 3.15 | 3.15 | |
| | | | 6.0 | 4.2 | 4.2 | 4.2 | |
| V _{IL} | Maximum Low-Level Input Voltage | V _{out} = 0.1 V or V _{CC} - 0.1 V I _{out} ≤ 20 μA | 2.0 | 0.3 | 0.3 | 0.3 | V |
| | | | 4.5 | 0.9 | 0.9 | 0.9 | |
| | | | 6.0 | 1.2 | 1.2 | 1.2 | |
| V _{OH} | Minimum High-Level Output Voltage | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 20 μA | 2.0 | 1.9 | 1.9 | 1.9 | V |
| | | | 4.5 | 4.4 | 4.4 | 4.4 | |
| | | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 4.0 mA I _{out} ≤ 5.2 mA | 4.5 | 3.98 | 3.84 | 3.70 | |
| | | | 6.0 | 5.48 | 5.34 | 5.20 | |
| V _{OL} | Maximum Low-Level Output Voltage | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 20 μA | 2.0 | 0.1 | 0.1 | 0.1 | V |
| | | | 4.5 | 0.1 | 0.1 | 0.1 | |
| | | V _{in} = V _{IH} or V _{IL} I _{out} ≤ 4.0 mA I _{out} ≤ 5.2 mA | 4.5 | 0.26 | 0.33 | 0.40 | |
| | | | 6.0 | 0.26 | 0.33 | 0.40 | |
| I _{in} | Maximum Input Leakage Current | V _{in} = V _{CC} or GND | 6.0 | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| I _{CC} | Maximum Quiescent Supply Current (per Package) | V _{in} = V _{CC} or GND I _{out} = 0 μA | 6.0 | 8 | 80 | 160 | μA |

NOTE: Information on typical parametric values can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

AC ELECTRICAL CHARACTERISTICS ($C_L = 50$ pF, Input $t_r = t_f = 6$ ns)

| Symbol | Parameter | VCC V | Guaranteed Limit | | | Unit |
|--|--|----------|------------------|--------|---------|------|
| | | | - 55 to 25°C | ≤ 85°C | ≤ 125°C | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Data to Output (Figures 1 and 6) | 2.0 | 185 | 230 | 280 | ns |
| | | 4.5 | 37 | 46 | 56 | |
| | | 6.0 | 31 | 39 | 48 | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Address Select to Output (Figures 2 and 6) | 2.0 | 215 | 270 | 325 | ns |
| | | 4.5 | 43 | 54 | 65 | |
| | | 6.0 | 37 | 46 | 55 | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Enable to Output (Figures 3 and 6) | 2.0 | 200 | 250 | 300 | ns |
| | | 4.5 | 40 | 50 | 60 | |
| | | 6.0 | 34 | 43 | 51 | |
| t _{PHL} | Maximum Propagation Delay, Reset to Output (Figures 4 and 6) | 2.0 | 155 | 195 | 235 | ns |
| | | 4.5 | 31 | 39 | 47 | |
| | | 6.0 | 26 | 33 | 40 | |
| t _{TLH} , t _{THL} | Maximum Output Transition Time, Any Output (Figures 1 and 6) | 2.0 | 75 | 95 | 110 | ns |
| | | 4.5 | 15 | 19 | 22 | |
| | | 6.0 | 13 | 16 | 19 | |
| C _{in} | Maximum Input Capacitance | — | 10 | 10 | 10 | pF |

NOTES:

- For propagation delays with loads other than 50 pF, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).
- Information on typical parametric values can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

| C _{PD} | Power Dissipation Capacitance (Per Package)* | Typical @ 25°C, VCC = 5.0 V | | pF |
|-----------------|--|-----------------------------|--|----|
| | | 30 | | |
| | | | | |

* Used to determine the no-load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$. For load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

TIMING REQUIREMENTS (Input $t_r = t_f = 6$ ns)

| Symbol | Parameter | VCC V | Guaranteed Limit | | | Unit |
|---------------------------------|---|----------|------------------|--------|---------|------|
| | | | - 55 to 25°C | ≤ 85°C | ≤ 125°C | |
| t _{su} | Minimum Setup Time, Address or Data to Enable (Figure 5) | 2.0 | 100 | 125 | 150 | ns |
| | | 4.5 | 20 | 25 | 30 | |
| | | 6.0 | 17 | 21 | 26 | |
| t _h | Minimum Hold Time, Enable to Address or Data (Figure 5) | 2.0 | 5 | 5 | 5 | ns |
| | | 4.5 | 5 | 5 | 5 | |
| | | 6.0 | 5 | 5 | 5 | |
| t _w | Minimum Pulse Width, Reset or Enable (Figure 3 or 4) | 2.0 | 80 | 100 | 120 | ns |
| | | 4.5 | 16 | 20 | 24 | |
| | | 6.0 | 14 | 17 | 20 | |
| t _r , t _f | Maximum Input Rise and Fall Times (Figure 1) | 2.0 | 1000 | 1000 | 1000 | ns |
| | | 4.5 | 500 | 500 | 500 | |
| | | 6.0 | 400 | 400 | 400 | |

NOTE: Information on typical parametric values can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

SWITCHING WAVEFORMS

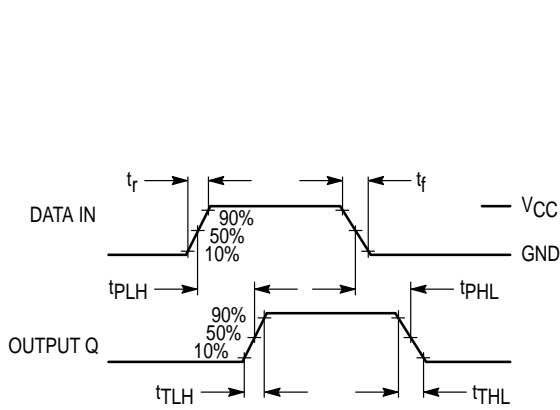


Figure 1.

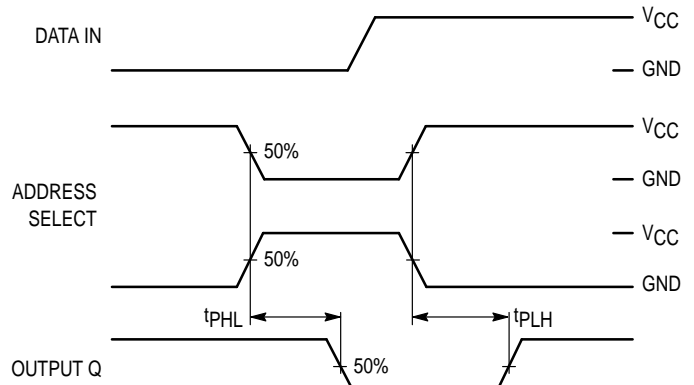


Figure 2.

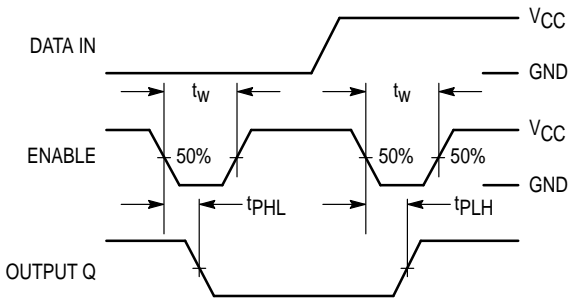


Figure 3.

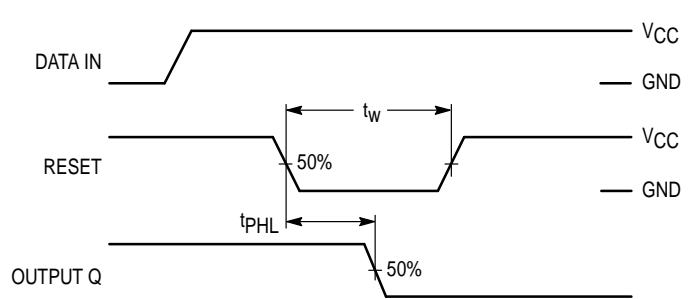


Figure 4.

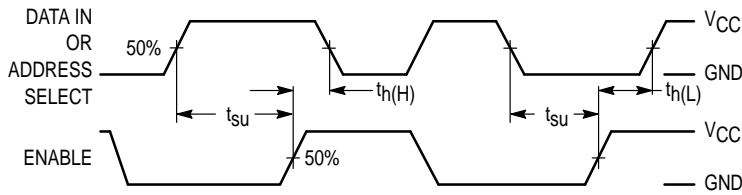
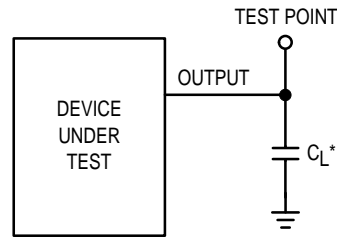


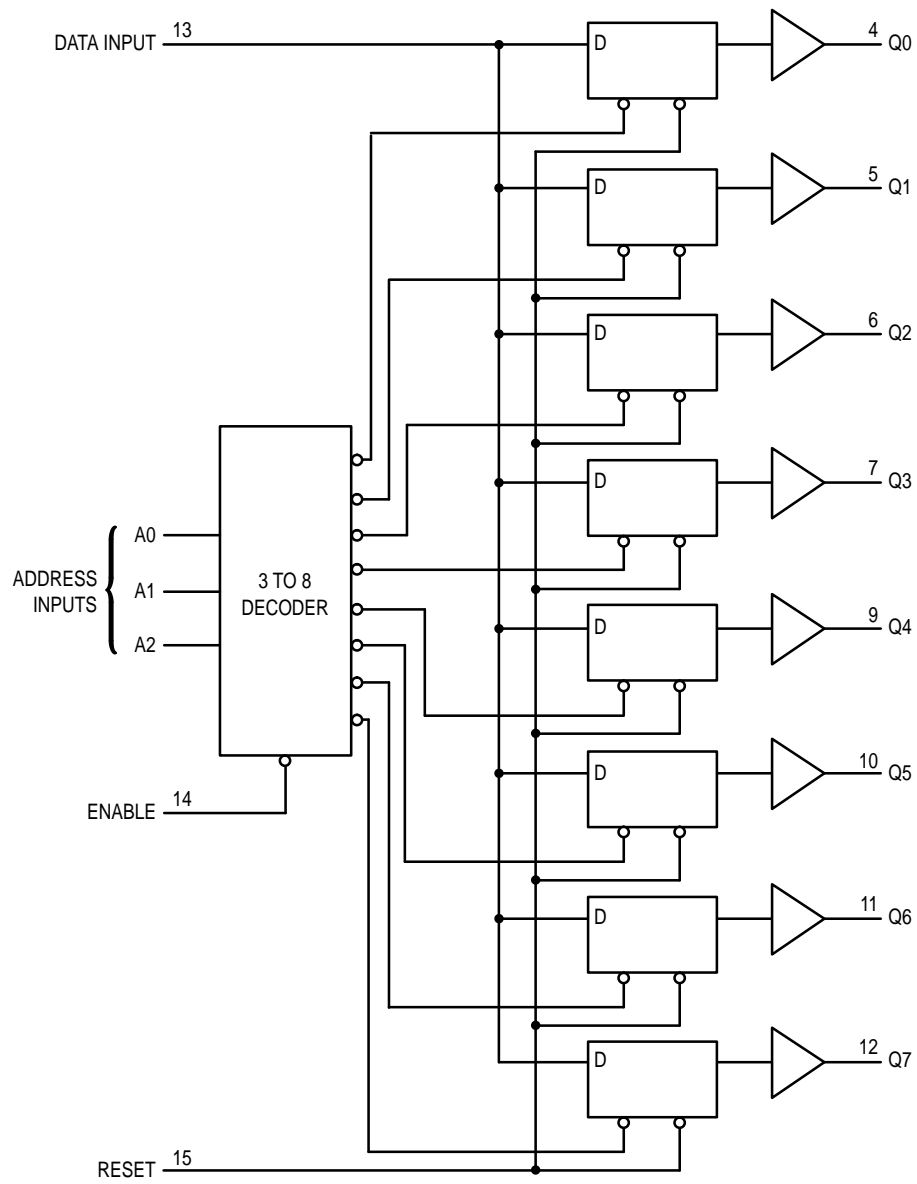
Figure 5.



* Includes all probe and jig capacitance

Figure 6. Test Circuit

EXPANDED LOGIC DIAGRAM



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